Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DSN1010-3 (SOT8007) Surface-Mounted Device (SMD) package using Trench MOSFET technology.

2. Features and benefits

- · Low threshold voltage
- Very fast switching
- Ultra small package: 0.96 × 0.96 × 0.24 mm
- Trench MOSFET technology

3. Applications

- Relay driver
- · Battery management
- · Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	12	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	14	Α
Static chara	cteristics						·
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ °C}$		-	13.2	16	mΩ

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), 4 layer copper, tin-plated and mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	D	drain		
3	S	source	Transparent top view DSN1010-3 (SOT8007)	G → → → → → → → → → → → → → → → → → → →

6. Ordering information

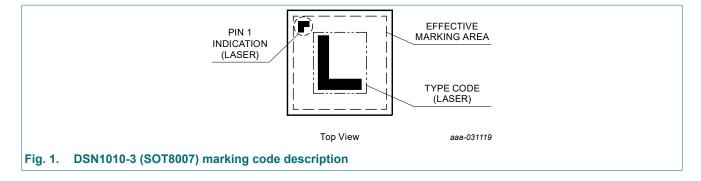
Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PMCA14UN	DSN1010-3	chip-scale package; 3 terminals; body 0.96 x 0.96 x 0.24 mm	SOT8007				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMCA14UN	L



8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	12	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	14	Α
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	11	Α
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	7	Α
I _{DM}	peak drain current	T _{amb} = 25 °C; single pulse; t _p ≤ 10 μs		-	44	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	1.2	W
			[1]	-	2.5	W
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.9	W
		T _{sp} = 25 °C		-	31	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	n diode			'		
Is	source current	T _{amb} = 25 °C	[1]	-	1.2	Α

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), 4 layer copper, tin-plated and mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), 4 layer copper, tin-plated and standard footprint.

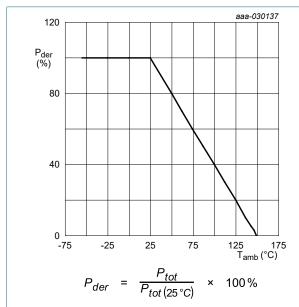


Fig. 2. Normalized total power dissipation as a function of ambient temperature

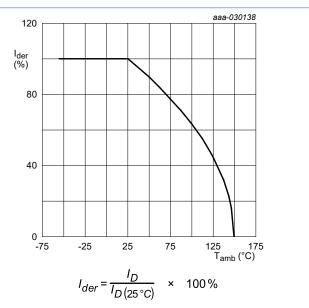


Fig. 3. Normalized continous drain current as a function of ambient temperature

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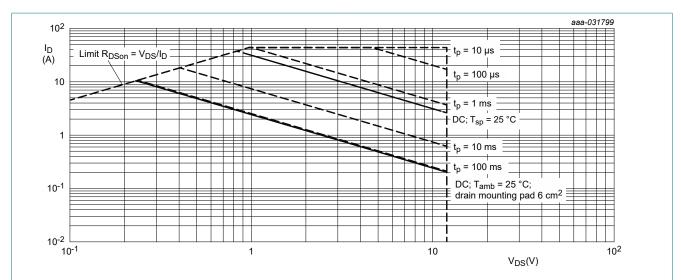


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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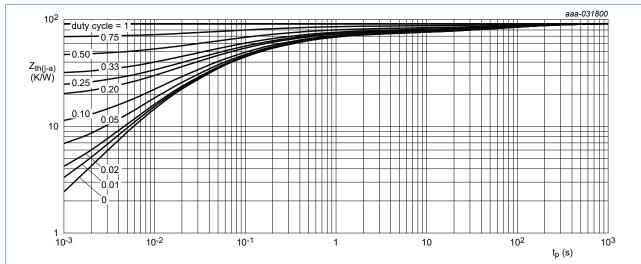
12 V, N-channel Trench MOSFET

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	92	106	K/W
	junction to ambient		[2]	-	43	50	K/W
		in free air; t ≤ 5 s	[2]	-	28	32	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	2	4	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), 4 layer copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), 4 layer copper, tin-plated and mounting pad for drain 6 cm².



FR4 PCB, 4 layer copper, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

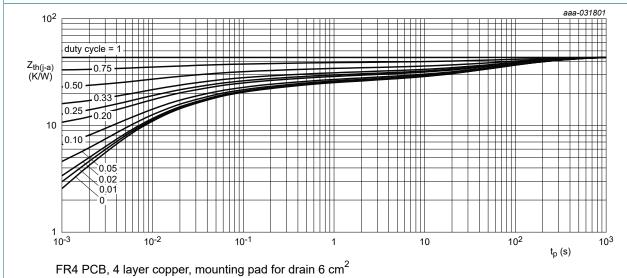


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 μ A; V_{GS} = 0 V; T_j = 25 °C	12	-	-	V
V_{GSth}	gate-source threshold voltage	I_D = 250 μ A; V_{DS} = V_{GS} ; T_j = 25 °C	0.4	0.6	0.9	V
I _{DSS}	drain leakage current	V _{DS} = 9.6 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	$V_{GS} = 4.5 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ °C}$	-	13.2	16	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 5 A; T _j = 150 °C	-	17	21	mΩ
		$V_{GS} = 3.3 \text{ V}; I_D = 5 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	14.2	17	mΩ
		V _{GS} = 2.5 V; I _D = 5 A; T _j = 25 °C	-	16	21	mΩ
		V _{GS} = 1.8 V; I _D = 1 A; T _j = 25 °C	-	22	35	mΩ
9 _{fs}	forward transconductance	V _{DS} = 6 V; I _D = 1 A; T _j = 25 °C	-	5.6	-	S
R_G	gate resistance	f = 1 MHz	-	1.5	-	Ω
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	$V_{DS} = 6 \text{ V}; I_D = 5 \text{ A}; V_{GS} = 3.3 \text{ V};$	-	8	12	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.3	-	nC
Q _{GD}	gate-drain charge	1	-	3.2	-	nC
C _{iss}	input capacitance	V _{DS} = 6 V; f = 1 MHz; V _{GS} = 0 V;	-	855	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	257	-	pF
C _{rss}	reverse transfer capacitance	_	-	237	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 6 \text{ V}; I_D = 5 \text{ A}; V_{GS} = 3.3 \text{ V};$	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 ^{\circ}C$	-	6	-	ns
t _{d(off)}	turn-off delay time	1	-	16	-	ns
t _f	fall time	1	-	11	-	ns
Source-dra	in diode	•	1		1	
V_{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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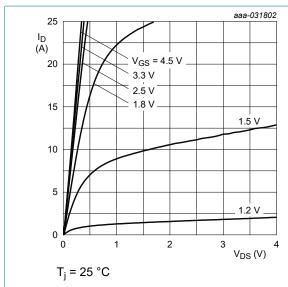


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

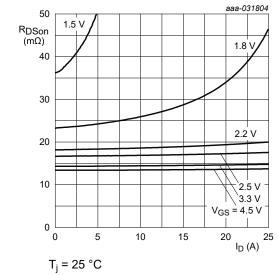


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

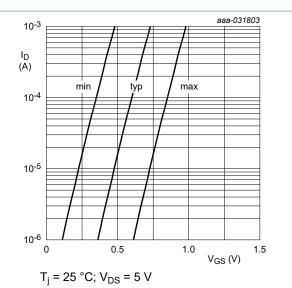


Fig. 8. Subthreshold drain current as a function of gate-source voltage

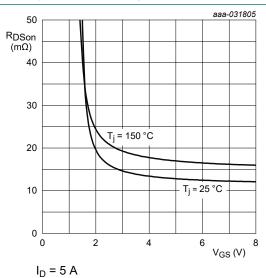


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

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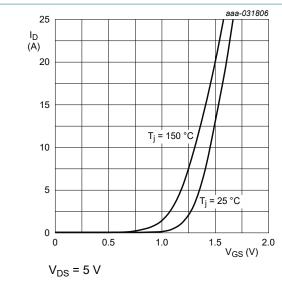


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

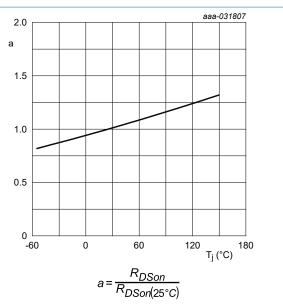


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

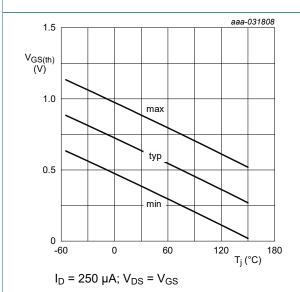
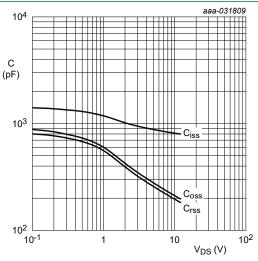


Fig. 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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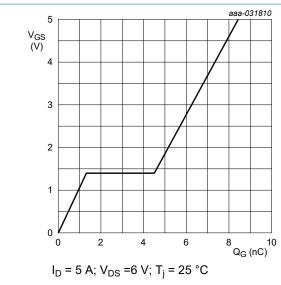


Fig. 15. Gate-source voltage as a function of gate charge; typical values

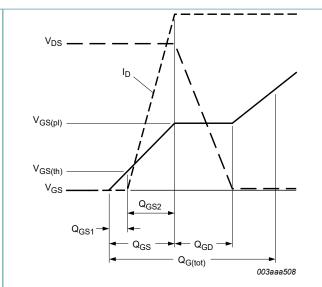


Fig. 16. Gate charge waveform definitions

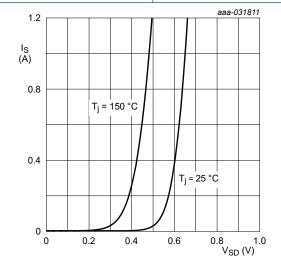
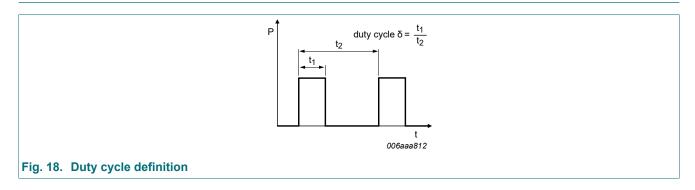


Fig. 17. Source current as a function of source-drain voltage; typical values

 $V_{GS} = 0 V$

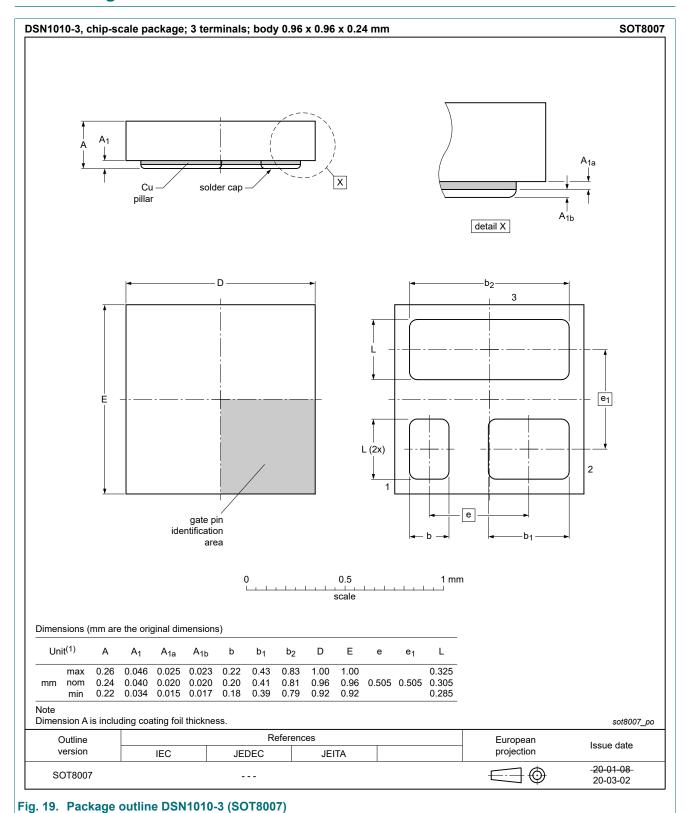
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11. Test information



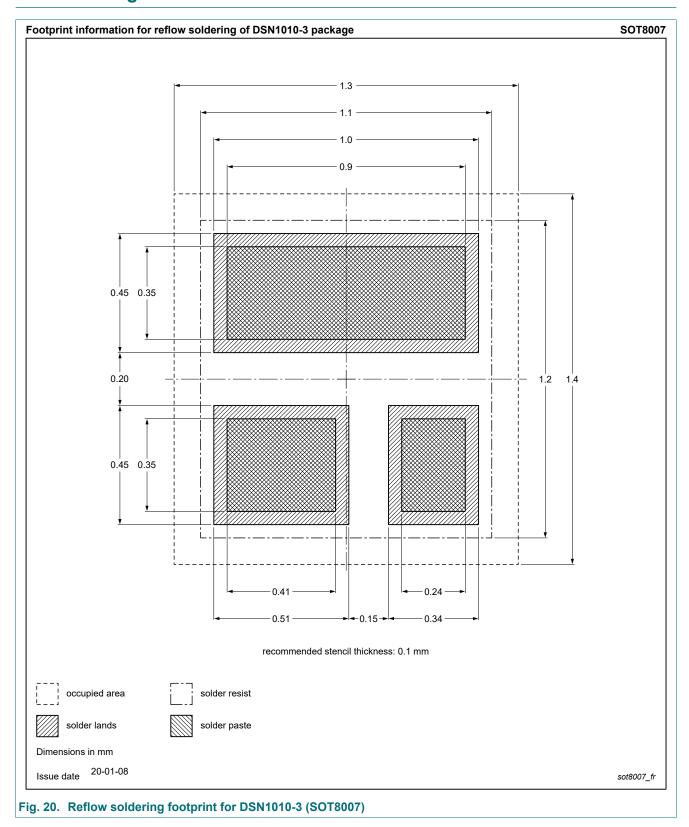
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCA14UN v.1	20200806	Product data sheet	-	-

12 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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